TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7MZ374FK

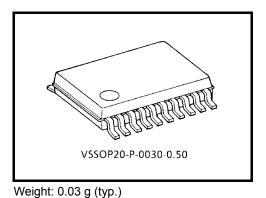
Low Voltage Octal D-Type Flip-Flop with 5 V Tolerant Inputs and Outputs

The TC7MZ374FK is a high performance CMOS octal D-type flip flop. Designed for use in 3.3 V systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5 V supply environment for both inputs and outputs.

This 8 bit D-type flip-flop is controlled by a clock input (CK) and a output enable input (\overline{OE}). When the \overline{OE} input is high, the eight outputs are in a high impedance state.

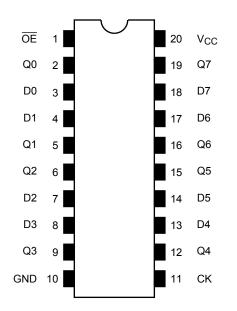
All inputs are equipped with protection circuits against static discharge.



- Features
- Low voltage operation: $V_{CC} = 2.0 \sim 3.6 \text{ V}$
- High speed operation: $t_{pd} = 8.5 \text{ ns} (max) (V_{CC} = 3.0 \sim 3.6 \text{ V})$
- Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA} (\text{min}) (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: -500 mA
- Package: VSSOP (US20)
- Power down protection is provided on all inputs and outputs.
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 374 type.

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Pin Assignment (top view)



Truth Table

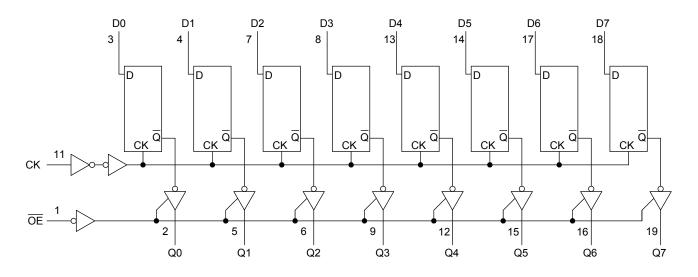
	Inputs	Outputs	
ŌĒ	СК	D	Outputs
Н	Х	Х	Z
L		Х	Qn
L		L	L
L		Н	Н

X: Don't care

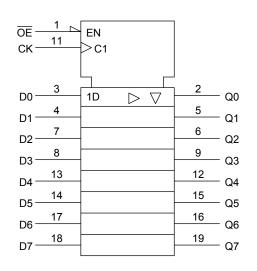
Z: High impedance

Qn: No change

System Diagram



IEC Logic Symbol



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~7.0	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC output voltage)/a=	-0.5~7.0 (Note 2)	V
DC oulput voltage	Vout	-0.5~V _{CC} + 0.5 (Note 3)	v
Input diode current	I _{IK}	-50	mA
Output diode current	IOK	±50 (Note 4)	mA
DC output current	IOUT	±50	mA
Power dissipation	PD	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65~150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 2: Output in off-state
- Note 3: High or low state. IOUT absolute maximum rating must be observed.
- Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$:

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit	
Supply voltage	2.0~3.6		V	
Supply vollage	V _{CC}	1.5~3.6 (Note 2)	v	
Input voltage	V _{IN}	0~5.5	V	
Output voltage	V _{OUT}	0~5.5 (Note 3)	V	
Output voltage		0~V _{CC} (Note 4)	v	
Output current	Іон/Іог	±24 (Note 5)	mA	
	'OH''OL	±12 (Note 6)	IIIA	
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dv	0~10 (Note 7)	ns/V	

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

- Note 3: Output in off state
- Note 4: High or low state
- Note 5: V_{CC} = 3.0~3.6 V
- Note 6: V_{CC} = 2.7~3.0 V
- Note 7: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

Electrical Characteristics

DC Characteristics (Ta = -40~85°C)

Characte	riation	Sumbol	Test Condition			Min	Maria	Linit
Characte	enstics	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Input voltage	High level	V _{IH}		—	2.7~3.6	2.0		V
input voltage	Low level	VIL		—	2.7~3.6	_	0.8	v
			I _{OH} = -100 μA	2.7~3.6	V _{CC} - 0.2	_		
	High level	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -12 mA	2.7	2.2		V
				I _{OH} = -18 mA	3.0	2.4		
Output voltage				I _{OH} = -24 mA	3.0	2.2		
Lewleyel	Mai		$I_{OL} = 100 \ \mu A$	2.7~3.6		0.2		
			I _{OL} = 12 mA	2.7		0.4		
	Low level	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 16 mA	3.0		0.4	
				I _{OL} = 24 mA	3.0	_	0.55	
Input leakage cu	ırrent	I _{IN}	V _{IN} = 0~5.5 V		2.7~3.6	_	±5.0	μA
3-state output of	f-state current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \sim 5.5 \text{ V}$		2.7~3.6	_	±5.0	μA
Power off leakag	ge current	IOFF	$V_{IN}/V_{OUT} = 5.5 V 0$		0	_	10.0	μA
Quiescent supply current			$V_{IN} = V_{CC}$ or GND		2.7~3.6	_	10.0	
Quiescent suppl	y current	Icc	V _{IN} /V _{OUT} = 3.6~5.5 V		2.7~3.6	_	±10.0	μA
Increase in I _{CC}	per input	∆l _{CC}	V _{IH} = V _{CC} - 0.6 V 2.7~		2.7~3.6		500	

AC Characteristics (Ta = -40~85°C)

Characteristics	Characteristics Symbol Test Condition			Min	Мах	Unit
Characteristics	Cymbol		V _{CC} (V)	IVIIII	Ινίαλ	Unit
Maximum clock frequency	f _{max}	Figure 1, Figure 2	2.7	_	—	MHz
Maximum clock frequency	יmax		$\textbf{3.3}\pm\textbf{0.3}$	150	_	
Propagation dolay time (CK (0)	t _{pLH}	Figure 1, Figure 2	2.7	_	9.5	ns
Propagation delay time (CK-Q)	t _{pHL}		$\textbf{3.3}\pm\textbf{0.3}$	1.5	8.5	115
Output enable time	t _{pZL}	Eiguro 1 Eiguro 3	2.7	_	9.5	ns
	t _{pZH}	Figure 1, Figure 3	$\textbf{3.3}\pm\textbf{0.3}$	1.5	8.5	115
Output disable time	t _{pLZ}	Figure 1, Figure 3	2.7	_	8.5	ns
Output disable time	t _{pHZ}		$\textbf{3.3}\pm\textbf{0.3}$	1.5	7.5	
Minimum nuloo width (CK)		2.7	4.0	_	20	
Minimum pulse width (CK)	t _w (L)	Figure 1, Figure 2	$\textbf{3.3}\pm\textbf{0.3}$	3.3	_	ns
Minimum oot un timo	+	Figure 1, Figure 2	2.7	2.5	_	20
Minimum set-up time	ts		$\textbf{3.3}\pm\textbf{0.3}$	2.5	_	ns
Minimum hold time	t.		2.7	1.5	_	20
	t _h	Figure 1, Figure 2	$\textbf{3.3}\pm\textbf{0.3}$	1.5	_	ns
	t _{osLH}	(Nista)	2.7			ns
Output to output skew	t _{osHL}	(Note)	3.3 ± 0.3		1.0	115

Note: This parameter is guaranteed by design.

 $(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$

Dynamic Switching Characteristics

(Ta = 25°C, Input: $t_r = t_f = 2.5 \text{ ns}, C_L = 50 \text{ pF}, R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V_{OL}	VOLP	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V
Quiet output minimum dynamic VOL	V _{OLV}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V

Capacitive Characteristics (Ta = 25°C)

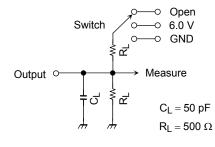
Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	—	3.3	7	pF
Output capacitance	C _{OUT}	_	3.3	8	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz (Not	e) 3.3	25	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation: $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per bit)

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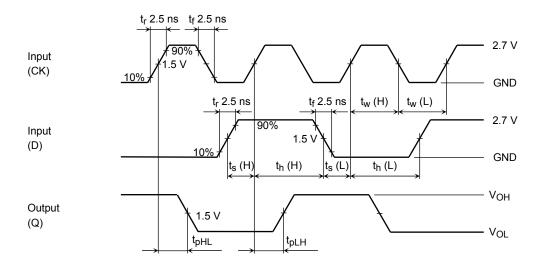
AC Test Circuit

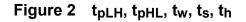


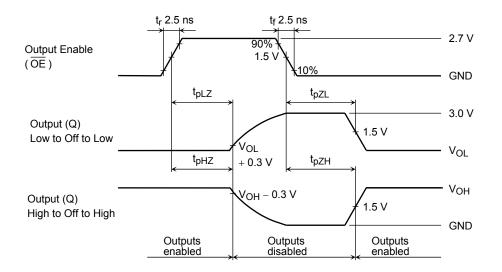
Parameter	Switch
t _{pLH} , t _{pHL}	Open
t _{pLZ} , t _{pZL}	6.0 V
t _{pHZ} , t _{pZH}	GND
t _w , t _s , t _h , f _{max}	Open

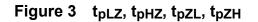
Figure 1

AC Waveform





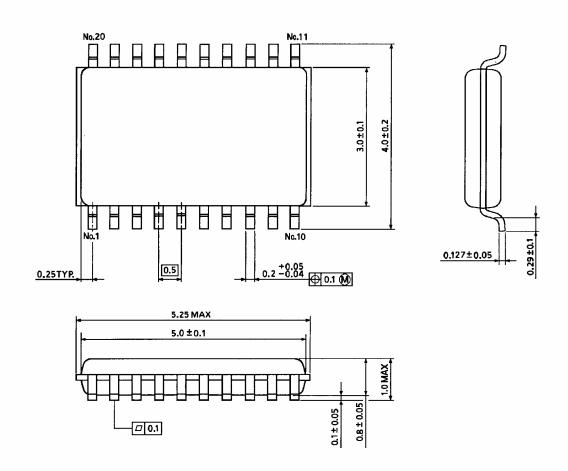




Package Dimensions

VSSOP20-P-0030-0.50

Unit : mm



Weight: 0.03 g (typ.)

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20070701-EN GENERAL

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